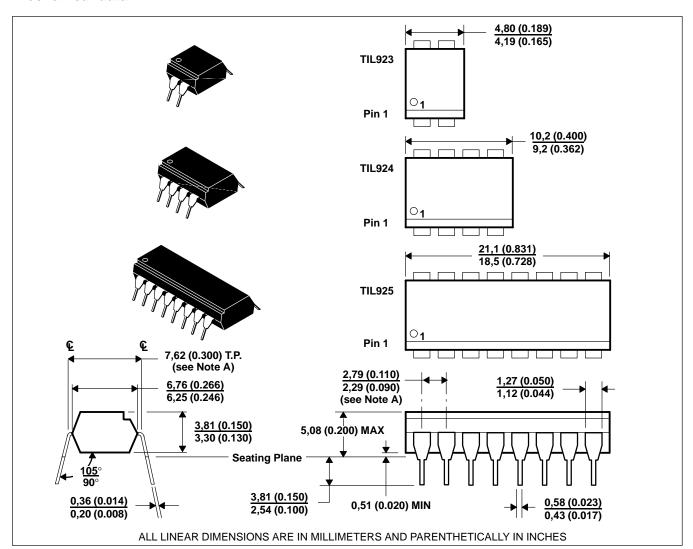
- Gallium-Arsenide Diode Infrared Source
- Source Is Optically Coupled to Silicon N-P-N Darlington Phototransistor
- Choice of One, Two, or Four Channels
- Choice of Two Current-Transfer Ratios
- High-Voltage Electrical Isolation . . . 7.5 kV Peak (5.3 kV rms)
- Plastic Dual-In-Line Packages
- UL Listed File No. E65085

description

These optocouplers consist of a gallium-arsenide light-emitting diode and a silicon n-p-n Darlington phototransistor per channel. The TIL923 has one channel in a 4-pin package, the TIL924 has two channels in a 8-pin package, and the TIL925 has four channels in a 16-pin package. The standard devices, TIL923, TIL924, and TIL925, are tested for a current-transfer ratio of 500% minimum. Devices selected for a current-transfer ratio of 1000% are designated with the suffix.

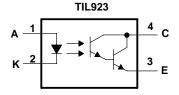
mechanical data

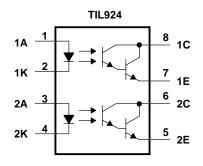


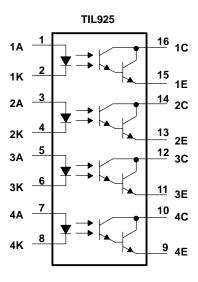
NOTE A: Each pin centerline is located 0,25 (0.010) of its true longitudinal position.



schematic diagrams







absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

Input-to-output voltage (see Note 1)	±7.5 kV peak or dc (±5.3 kV rms)
Collector-emitter voltage (see Note 2)	35 V
Emitter-collector voltage	7 V
Input diode reverse voltage	5 V
Input diode continuous forward current at (or below) 25°C free-air tempe	erature (see Note 3) 50 mA
Continuous power dissipation at (or below) 25°C free-air temperature:	
Phototransistor (see Note 4)	150 mW
Input diode plus phototransistor per channel (see Note 5)	
Operating free-air temperature, T _A	–55°C to 100°C
Storage temperature range	–55°C to 125°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- NOTES: 1. This rating applies for sine-wave operation at 50 or 60 Hz. Service capability is verified by testing in accordance with UL requirements.
 - 2. This value applies when the base-emitter diode is open circuited.
 - 3. Derate linearly to 100°C free-air temperature at the rate of 0.67 mA/°C.
 - 4. Derate linearly to 100°C free-air temperature at the rate of 2 mW/°C.
 - 5. Derate linearly to 100°C free-air temperature at the rate of 2.67 mW/°C.

electrical characteristics, T_A = 25°C (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _(BR) CEO	Collector-emitter breakdown voltage		$I_C = 0.5 \text{ mA},$	I _F = 0		35			V
V(BR)ECO	Emitter-collector breakdown voltage		$I_C = 100 \mu A$,	lF = 0		7			V
I_{R}	Input diode static reverse current		V _R = 5 V					10	μΑ
IC(off)	Off-state collector current		V _{CE} = 10 V,	lF = 0				100	nA
CTR	Current transfer ratio	TIL923, TIL924, TIL925	IF = 2 mA,	V _{CE} = 1 V		500%			
		TIL923A, TIL924A, TIL925A				1000%			
٧F	Input diode static forward voltage		IF = 20 mA					1.4	V
VCE(sat)	Collector-emitter saturation voltage		IF = 10 mA,	$I_C = 50 \text{ mA}$				1	V
Cio	Input-to-output capacitance		$V_{in-out} = 0$,	f = 1 MHz,	See Note 6		1		pF
r _{io}	Input-to-output internal resistance		$V_{in-out} = \pm 1 \text{ kV},$	See Note 6			1011		Ω

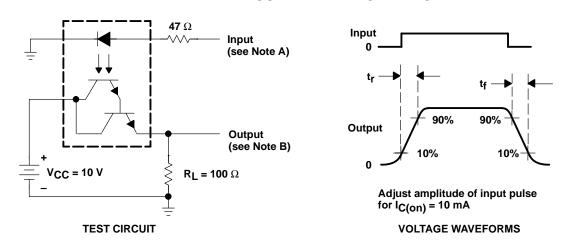
NOTE 6. These parameters are measured between all input-diode leads shorted together and all phototransistor leads shorted together.



switching characteristics at 25°C free-air temperature

L	PARAMETER	TEST CONDITIONS	MIN	TYP I	MAX	UNIT
ŀ	r Rise time	$V_{CC} = 10 \text{ V}, I_{C(\Omega D)} = 10 \text{ mA}, R_{I} = 100 \Omega, \text{See Figure 1}$		100		μs
Ŀ	f Fall time	$V_{CC} = 10 \text{ V}, I_{C(on)} = 10 \text{ mA}, R_L = 100 \Omega, \text{See Figure 1}$		100		

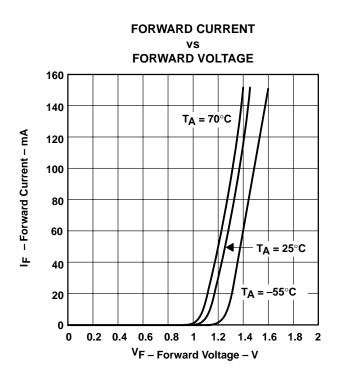
PARAMETER MEASUREMENT INFORMATION

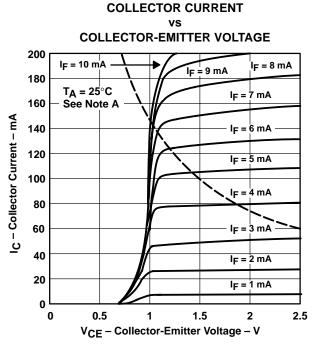


NOTES: A. The input waveform is supplied by a generator with the following characteristics: $Z_0 = 50 \,\Omega$, $t_r \le 15 \,\text{ns}$, duty cycle = 1%, $t_W = 500 \,\mu\text{s}$. B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_r \le 12 \,\text{ns}$, $R_{in} \ge 1 \,\text{M}\Omega$, $C_{in} \le 20 \,\text{pF}$.

Figure 1. Switching Times

TYPICAL CHARACTERISTICS



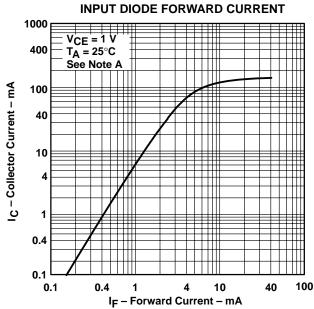


NOTE A: Pulse operation is required for operation beyond limits shown by the dashed line.

Figure 3

Figure 2





NOTE A: These parameters are measured using pulse techniques $t_W = 1 \text{ ms}$, duty cycle $\leq 2\%$.

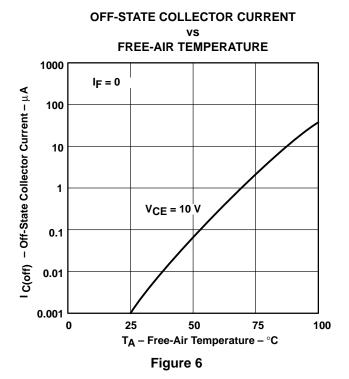
Figure 4



TYPICAL CHARACTERISTICS

RELATIVE ON-STATE COLLECTOR CURRENT FREE-AIR TEMPERATURE 1.2 Collector Current Relative to Value at TA = 25 $^{\circ}\text{C}$ V_{CE} = 1 V IF = 10 mA lF = 2 mA 0.8 I_F = 10 mA 0.6 0.4 IF = 2 mA 0.2 -75 -50 -25 25 75 100 $T_{\mbox{A}}$ – Free-Air Temperature – $^{\circ}\mbox{C}$

Figure 5







ti.com 8-Apr-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TIL923	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TIL923A	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TIL924	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TIL924A	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TIL925	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI
TIL925A	OBSOLETE	PDIP	Р	8	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

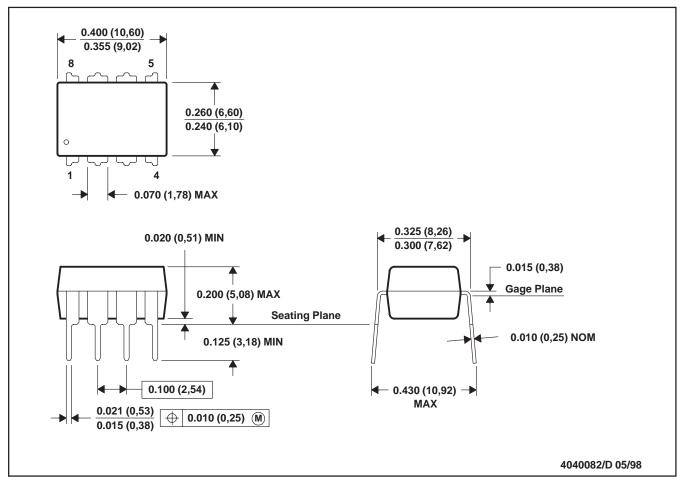
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

For the latest package information, go to $http://www.ti.com/sc/docs/package/pkg_info.htm$

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